Above-room -tem perature ferrom agnetism in half-m etallic H eusler com pounds N iC rP,
N iC rSe, N iC rTe and N iVA s: A rst{principles study

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We study the interatom ic exchange interactions and Curie temperatures in half{metallic semi Heusler compounds NiCrZ (Z=P,Se,Te) and NiVAs. The study is performed within the framework of density functional theory. The calculation of exchange parameters is based on the frozen{magnon approach. It is shown that the exchange interactions in NiCrZ vary strongly depending on the Z constituent. The Curie temperature,  $T_{\rm c}$ , is calculated within the mean eld and random phase approximations. The dierence between two estimations is related to the properties of the exchange interactions. The predicted Curie temperatures of all four systems are considerably higher than room temperature. The relation between the half-metallicity and the value of the Curie temperature is discussed. The combination of a high spin-polarization of charge carriers and a high Curie temperature makes these Heusler alloys interesting candidates for spintronics applications.

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#### INTRODUCTION

An important current problem on the way to the practical use of the spin-transport in sem iconductor devices is the fabrication of the materials that make possible the in jection of spin-polarized electrons into a sem iconductor at room temperature [1]. One of the classes of systems promising to supply materials with necessary combination of properties is the half(m etallic ferrom agnets, ie., ferrom agnetic system swhere one spin channel is metallic and other is sem iconducting. The half-m etallicity leads to the 100% spin-polarization of the electron states at the Ferm i level  $E_F$  [2, 3]. The half(m etallic ferrom agnetism (HMF) was discovered by de Groot et al. when studying the band structure of sem i Heusler compound NiM nSb [4]. Ishida et al. have proposed that also the full-Heusler alloys of the type  $Co_2M$  nZ, (Z=Si,Ge), are half-m etals [5]. Since then a number of further systems were predicted to be half-metallic. Among them binary magnetic oxides (CrO<sub>2</sub> and Fe<sub>3</sub>O<sub>4</sub>), colossal magnetoresistance m aterials ( $Sr_2$ FeM oO  $_6$  and  $La_{0:7}Sr_{0:3}$ M nO  $_3$ ) [6], diluted magnetic semiconductors (Ga<sub>1 x</sub>M n<sub>x</sub>As) and zincblende com pounds M nAs and CrAs [7, 8, 9].

The Heusler alloys form a particularly interesting class of materials since they are characterized by a high Curie temperature and good crystallographic compatibility with the lattices of semiconductors used industrially [10, 11, 12]. The main body of previous rst-principles studies was focused on the investigation of the properties of the semiconducting gap in the minority-spin channel. Galanakis et al. considering NiMnSb have shown that the gap arises from the interaction between the d-orbitals of the Ni and Mn atoms leading to the formation of bonding and antibonding states separated by a hybridizational gap [13]. Chioncel et al. have demonstrated by the example of NiMnSb that the electron-magnon interaction can lead to the appearance of nonquasiparticle states in

the half-m etallic gap [14].

For a number of Heusler alloys it was shown that half(metallicity is preserved under tetragonalization of the crystal lattice [15] and application of the hydrostatic pressure [16]. Mavropoulos et al. studied the inuence of the spin-orbit coupling on the spin-polarization at the Fermi level and found the elect to be very small [17] that corresponds to a small orbital moment calculated by Galanakis [18]. Orgassa and collaborators have shown that the half-metallic gap decreases with increasing disorder [19]. Picozzi and collaborators and Miura et al. demonstrated that dierent types of structural defects have dierent in uence on the half-metallicity [19, 20, 21].

An important part of theoretical e orts is a rst-principles design of new half(m etallic Heusler alloys. Galanakis studied the appearance of half-m etallic ferromagnetism in quaternary Heusler alloys [22]. Xing et al. have predicted the half(m etallic ferromagnetism in NiCrZ (Z=P,Se,Te) and NiVAssemiHeuslercompounds [23,24].

D espite a very strong experim ental and theoretical interest to the half-m etallic ferrom agnetism in Heusler alloys the number of the studies of the exchange interactions in Heusler alloys is still very small. The rst contribution to the density functional theory of the exchange interactions in these systems was made in an early paper by Kubler et. al., [25] where the microscopic mechanisms of the magnetism of Heusler alloys were discussed on the basis of the comparison of the ferrom agnetic and antiferrom agnetic congurations of the Mn moments. Recently, the studies of the inter-atomic exchange interactions in several Heusler compounds were reported by the present authors and Kurtulus et al. [26, 27, 28, 29].

The purpose of the present work is a rst{principles study of the exchange interactions and the temperature of magnetic phase transition for four semilHeusler

compounds NiCrZ (Z=P,Se,Te) and NiVAs that were recently predicted to be half-metals [23,24]. For all four systems we not the Curie temperature substantially exceeding room temperature. We discuss the relation between the value of the Curie temperature and half-metallicity. We demonstrate strong dependence of the elective exchange interaction between 3d atoms on the spelement (Z constituent).

The paper is organized as follows. In Sec. II we present the calculational approach. Section III contains the results of the calculations and discussion. Section IV gives the conclusions.

#### COMPUTATIONAL METHOD

The semiHeusler compounds crystallize in the C  $1_{\rm b}$  type structure. The lattice consists of three interpenetrating fcc atomic sublattices. Compared with full Heusler alloys the forth atomic sublattice is vacant. In the calculations, the atomic positions of the fourth sublattice are occupied by empty spheres.

The calculations are carried out with the augmented spherical waves method [30] within the atom ic{sphere approximation (ASA)[31]. The exchange{correlation potential is chosen in the generalized gradient approximation [32]. A dense Brillouin zone (BZ) sampling 30 30 is used.

For each compound we performed calculations for two values of the lattice parameter: the theoretical equilibrium parameter [23,24] and the lattice parameter of a binary semiconductor (Table I) that can be considered as a possible substrate for growing the corresponding Heusler alloy: GaAs for NiCrP and NiCrSe and InP for NiVAs and NiCrTe. The radii of all atom ic spheres are chosen equal.

To calculate the interatom ic exchange interactions we use the frozen-magnon technique [33] and map the results of the calculation of the total energy of the helical magnetic congurations

$$s_n = (\cos(qR_n) \sin ; \sin(qR_n) \sin ; \cos)$$
 (1)

onto a classical H eisenberg H am iltonian

$$H_{eff} = J_{ij}s_is_j$$
 (2)

where  $J_{ij}$  is an exchange interaction between two Cr (V) sites and  $s_i$  is the unit vector pointing in the direction of them agneticm oment at site i, R<sub>n</sub> are the lattice vectors, q is the wave vector of the helix, polar angle giving the deviation of the moments from the z axis. W ithin the H eisenberg model (2), the energy of frozen-magnon con gurations can be represented in the form

$$E(;q) = E_0() + \sin^2 J(q)$$
 (3)

TABLE I:Lattice param eters and m agnetic m om ents (in  $_{\rm B}$  ) of N iVAs, N iC rZ (Z=P, Se, Te) and N iM nSb.

	a(A)	Νi	V ,C r,M n	Void	Z	Cell
NÌVAs	5.85	-0.02	2.05	0.06	-0.09	2.0
	5.87 <sub>(InP)</sub>	-0.03	2.06	0.06	-0.09	2.0
N iC rP	5.59	-0.01	3 <b>.</b> 08	0.07	-0.15	3.0
	$5.65_{(G aA s)}$	-0.06	3.16	0.06	-0.16	3.0
N iM nSb (a)	5 <b>.</b> 64	0.19	3.86	0.04	-0.10	4.0
N iC rSe	5 <b>.</b> 64	0.24	3 <b>.</b> 64	0.12	-0.01	4.0
	$5.65_{(G aA s)}$	0.23	3 <b>.</b> 65	0.12	-0.01	4.0
NiCrTe	5.84	0.24	3 <b>.</b> 68	0.11	-0.03	4.0
	5.87 <sub>(InP)</sub>	0.23	3.70	0.11	<b>-0.03</b>	4.0

<sup>(</sup>a) Ref.28

where  $E_0$  does not depend on q and J(q) is the the Fourier transform of the parameters of exchange interaction between pairs of Cr(V) atom s:

$$J(q) = \begin{cases} X \\ J_{0R} & \exp(iq R) \end{cases}$$
 (4)

Calculating E ( ;q) for a regular q{m esh in the Brillouin zone of the crystal and perform ing back Fourier transform ation one gets exchange parameters  $J_{0R}$  between pairs of Cr(V) atom s.

The Curie tem perature is estimated in the mean-eld approximation (MFA)

$$k_B T_C^{M FA} = \frac{2}{3} \frac{X}{160} J_{0j} = \frac{M}{6B} \frac{1}{N} \frac{X}{q} ! (q)$$
 (5)

and random phase approximation (RPA)

$$\frac{1}{k_{\rm B} T_{\rm C}^{\rm RPA}} = \frac{6_{\rm B}}{M} \frac{1}{N} \frac{X}{1} \frac{1}{! (q)}$$
 (6)

where ! (q) =  $\frac{4}{M}$  [J (0) J (q)] is the energy of spin {wave excitations.

#### RESULTS AND DISCUSSION

# D O S and m agnetic m om ents

The two lattice parameters used in the calculations resulted for all systems in very similar physical properties (see, e.g., Tables I,II). Therefore the most of the results will be presented for one lattice constant. All the discussion in this section is valid for both lattice spacings.

In Fig. 1, we present the calculated electron densities of states (DOS) of the ferrom agnetic states of the four Heusler compounds. All systems are found to be half-metallic with the Fermilevellying in the semiconducting gap of the minority-spin channel. Our DOS are in good agreement with the DOS presented in Refs.[23, 24].

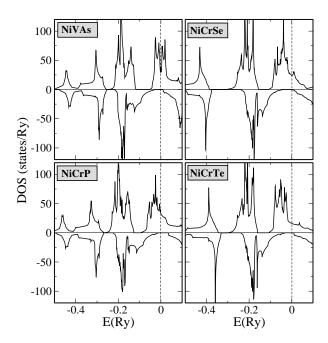


FIG. 1: Spin {projected total density of states of N iVAs and N iC rZ (Z=P, Se, Te)

In Table I, the calculated m agnetic m om ents are collected. Since the systems are half-m etallic, the m agnetic m om ents per formula unit are integer: 2  $_{\rm B}$  for N iVAs, 3  $_{\rm B}$  for N iC rP and 4  $_{\rm B}$  for N iC rSe and N iC rTe. Them appropriate of the magnetic m om ent comes from the second formula atom (V,Cr). Small induced magnetic moments are found on N i and sp atoms.

# Exchange constants and Curie temperature

Figure 2a presents the frozen-magnon dispersion for one direction in the reciprocal space. Additionally to NiCrZ (Z=P, Se, Te) and NiVAswe present for comparison the results for NiM nSb [28]. The ve systems can be subdivided into two groups. One group contains N N/As, N iC rP and N iM nSb. Here the frozen-m agnon dispersions are monotonous and resemble, visually, a simple cosinusoid. The second group contains NiCrSe and NiCrTe and is characterized by nonmonotonous dispersions with a maximum close to the center of the q-interval (Fig. 2a). Note, that the sp elements (the third chemical-formula constituents) within each of the group belong to the sam e column of the M endeleev's table whereas for dierent groups these columns are dierent. The importance of the valency of the sp element for magnetic properties of Heusler alloys has been already observed in our earlier studies [26].

The calculated exchange parameters are given in Fig. 2b. Since the inter-atom ic exchange parameters are the Fourier transforms of the frozen-magnon dispersions

they re ect the properties of the dispersions: The exchange parameters belonging to the same group show similar qualitative behavior. On the other hand, there is strong dierence between the systems belonging to different groups (Fig. 2b). In the 1st group (Fig. 2b, left panel), the strongest exchange interaction takes place between nearest magnetic 3d atoms. This strongest interaction determines the cosinusoidal form of the corresponding magnon dispersion. The sizable interaction between the second-nearest magnetic 3d atoms describes the deviation of the dispersion from a simple cosinusoid.

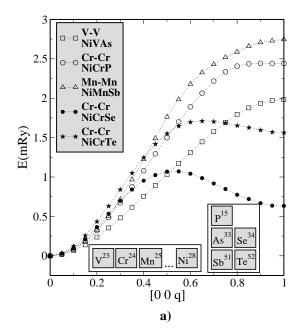
In the second group of compounds (Fig. 2b, right panel), the strongest interaction is between the second-nearest magnetic atom s. Because of the decreased period of the Fourier component corresponding to the second exchange parameter the dispersions are nonmonotonous and have the maximum not at the boundary of the Brilbuin zone but inside of it.

A remarkable feature of the exchange interactions is their short range character: the leading contribution into the Curie temperature of all systems is provided by the interactions within the rst two coordination spheres. The interactions with further coordination spheres are very weak and can be neglected in the calculation of the Curie temperature. The interaction between Ni atoms and the interaction of Niwith V and Cr are very weak and are not presented.

The calculated exchange param eters are used to evaluate the Curie temperature (Table II). It is important to note that the similarity of the form of the magnon dispersions within one group of compounds is not accompanied by a quantitative closeness of the curves (Fig. 2a). Therefore the Curie temperature can dier strongly for compounds belonging to the same group.

The Curie tem peratures are estim ated within two different schemes: MFA and RPA. For all systems and for both theoretical schemes the calculated Curie temperatures are substantially higher than room temperature. The MFA always gives the value of  $T_{\rm c}$  that is larger than the corresponding RPA value and usually overestimates the experimental Curie temperature [37, 38]. The reason for the dierence of the MFA and RPA estimations is a dierent weighting of the spin-wave excitations within two calculational approaches: The MFA takes all excitations with the same weight whereas the RPA gives a larger weight to the excitations with lower energy. The RPA weighting is better grounded from the viewpoint of statistical mechanics.

The analysis of the calculational data allows to make a number of important conclusions. First, there is a strong in uence of the sp atom on the value of  $T_{\rm c}$ . Indeed, the comparison of N iC rSe and N iC rTe that dier by the sp atom shows that the Curie temperature changes from about 500 K in N iC rSe to about 800 K in N iC rTe. This strong dependence reveals the sensitivity of the exchange interactions and the Curie temperature to the details of



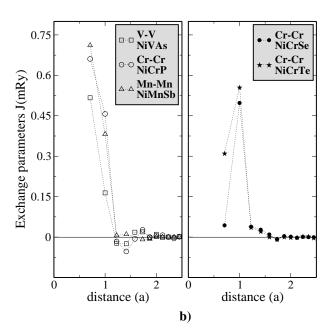


FIG. 2: a) Frozen {m agnon energies as a function of the wave vector q (in units of 2 =a) in N iVAs, N iM nSb and N iCrZ (Z=P, Se, Te) for V {V, M n {M n and Cr{Cr interactions, respectively. b) Interatom ic exchange interactions in N iCrZ (Z=P, Se, Te) and N iVAs. The distances are given in the units of the lattice constant. The calculational data for N iVAs and N iCrZ are presented for the theoretical equilibrium lattice constant. The data for N iM nSb are from Ref. [28].

the electron structure.

An interesting feature of the calculated C urie tem peratures (Table II) is a large di erence between the M FA and RPA estimations for the rst group of compounds in contrast to a small di erence for the second group. Characterizing the relative di erence of the M FA and RPA values of the C urie temperature by the relation  $[\Gamma_c^{MFA} \quad T_c^{RPA}] = T_c^{RPA}$  we get for the rst group of compounds a large value of 20-24% compared to a small value of 5-8% in the second group. This feature re ects the properties of the corresponding frozen-magnon spectra.

In MFA, the Curie temperature is determined by an arithmetic average of the magnon energies while in RPA  $T_{\rm c}$  is determined by the harmonic average of the same quantities (the rst average is always larger than the second). In terms of magnon energies,  $T_{\rm c}^{\rm MFA}$  is equal to  $T_{\rm c}^{\rm RPA}$  in the case that the magnon spectrum is dispersion-less: the magnon energy does not depend on the wave vector  ${\bf g}$ .

From Fig. 2 we see that the frozen {m agnon curves of the second group of com pounds are at in the second half of the q interval dem onstrating here a very weak dispersion. On the other hand, the rst group of com pounds have considerable dispersion in this part of the q interval. C om paring now the low-q parts of the curves we notice that the curves of the second group of com pounds lie higher than the rst group. Therefore, the relative contribution of the low-energy m agnons to the RPA value of the C urie tem perature is smaller in the second group of

com pounds.

This combination of features of the wave-vector dependencies of the frozen-magnon energies is responsible for a larger (smaller) dierence between the RPA and MFA estimations of the Curie temperature of the rst group (second group) of compounds in the two cases.

# Curie tem perature and half-m etallicity

An important question concerning the magnetism of the half-metallic systems is the relation between half-metallicity and Curie temperature. Indeed, a number of studies has shown that the half-metallicity can stimulate an increase of the Curie temperature [39, 40, 41]. The analysis of Fig. 3 allows us to establish a correlation between the value of the Curie temperature and the energy distance between the Fermi level and the upper edge of the semiconducting gap. This quantity determines the spacing between the highest occupied spin-up state and the lowest empty spin-down state. For very small of 0.03 eV in Nicrse we obtained the lowest Curie temperature of 508 K.On the other hand, for large in NicrP and Nim Nsb we obtained the Curie temperature substantially above 800 K.

Since the value of the C urie tem perature is determ ined by the m agnetic excitations to interpret the  $$T_{\rm c}$$  correlation we need to understand the origin of the in uence of the \$ value on the spin-wave energies.

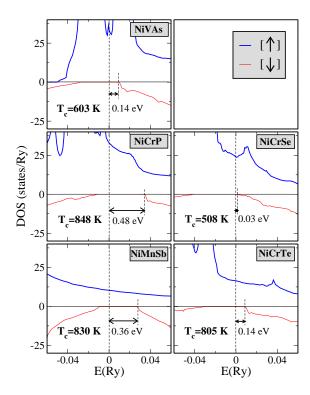


FIG. 3: Spin {projected total density of states of N NAs, N ic rP, N im nSb, N ic rSe and N ic rTe near Ferm i level. A lso shown are the RPA estimations of the Curie temperature and the energy distances between the Ferm i level and the bottom of the spin-down conduction band.

The magnon energies reect the energy prize for the deviations of the atom ic m om ents from parallel directions [34, 35, 36]. In the ground-state ferrom agnetic con guration the spin-projection is a good quantum number and the electron states with opposite spin projections do not interact. The deviation of the atom ic m om ents from parallel directions leads to the mixing of the majorityspin and minority-spin states. The hybridization of a pair of the states leads to their repulsion. As a result, the energy of the lower state decreases (bonding state) and the energy of the upper state increases (antibonding state). If the lower state is occupied and the upper state is empty this process leads to the decrease of the energy of the magnon making ferrom agnetic state energetically less favorable. The smaller is the energy distance between interacting states the stronger is the e ect.

Coming back to the halfmetallic compounds considered in the paper we note that the hybridizational interaction of this type takes place between the occupied majority-spin states below the Fermilevel and the empty spin-down states at the bottom of the conduction band. The distance between these states is given by parameter.

. Therefore this process provides a mechanism for the correlation between and Curie temperature.

Since the strength of the hybridizational repulsion in-

TABLE II: M FA and RPA estim ations of the Curie tem peratures in N iVA s, N iC rZ (Z=P, Se, Te) and N iM nSb. The third column represent the relative dierence of the M FA and RPA estimations.

	T [M F A ] (K )	T <sub>c</sub> [R P A ] (K )	Tc[MFARPA]
NiVAs	723	603	응 20
N iVA s <sup>(a)</sup>	715	595	% 20
N iC nP	1030	848	% 21
NiCiP <sup>(b)</sup>	938	770	% 22
N iM nSb (c)	1096	880	% 24
N iC rSe	537	508	응 6
N iC rSe(b)	543	515	% 5
NiCrTe	868	805	% 8
N iC rTe <sup>(a)</sup>	874	812	% 8

- (a) lattice constant of G aA s
- (b) lattice constant of InP
- (c) Ref.28

creases with decreasing energy distance between interacting states the negative contribution to the spin-wave energies is larger in the case of smaller . However, the correlation between param eter and Tc or, m ore general, between the half-m etallicity and  $T_{\rm c}$  should not be considered as a universal rule. The hybridizational repulsion considered above is only one of num erous processes arising in a complex multi-band system with the deviation of the atom ic m om ents from the parallel directions. The combined result of these processes cannot be predicted without the direct calculation of the excitation energies. Such a calculation must take into account the complexity of the electron structure of a real system. Indeed, the comparison of N NAs and NiCrTe shows that both systems have the same of 0.14eV. However, their Curie tem peratures di er strongly.

A lso our num erical experim ents with varying the lattice param eter in half-m etallic systems have shown that in some systems the loss of the half-m etallicity caused by this variation does not lead to the decrease of the Curie temperature [28].

### CONCLUSION

We have system atically studied exchange interactions and Curie temperature in predicted half(metallic semi Heusler compounds NiVAs and NiCrZ (Z= P, Se, Te). The calculations are performed within the parameter free density functional theory. The RPA and MFA are used to estimate the Curie temperatures. We show that the behavior of exchange interactions in these systems vary strongly depending on the Z constituent.

The exchange interactions are short range with the leading contribution to the Curie temperature provided by the interactions within the rst two coordination

spheres of the magnetic 3d atoms. The predicted Curie temperatures of all four systems are considerably higher than room temperature. The relation between the half-metallicity and the value of the Curie temperature is discussed. The combination of a high spin-polarization of charge carriers and a high Curie temperature makes these Heusler alloys interesting candidates for spintronics applications. We hope that the present study will provide a guideline for experimental work stimulating the fabrication of these materials

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